

REMARKS

In reviewing the file of the above-identified application, it was discovered that a typographical error was made in the application number of the French priority application on the declaration. The application number was inadvertently indicated as "FR 0216049"; the correct number is "FR 0216409". A copy of the Declaration is enclosed on which the applicants' attorney has made and initialed the change to the French application number. It is further noted that a copy of the correct priority document, French application no. 02 16409, was filed on May 7, 2004 to perfect the priority claim. Furthermore, the filing receipt has been updated to show the correct number, but the Bibliographic Data Sheet on PAIR (copy attached) has not been updated. Applicants hereby request that the Data Sheet also be updated so that the correct information appears on the patent, and have denoted the correction on the enclosed copy.

Respectfully submitted,

Date

11/2/05



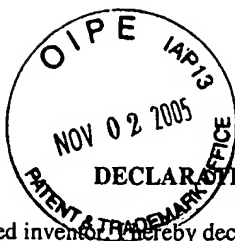
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212-294-3311



DECLARATION FOR NON-PROVISIONAL PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below at 201 et seq. beneath my name.

I believe I am the original, first and sole inventor if only one name is listed at 201 below, or an original, first and joint inventor if plural names are listed at 201 et seq. below, of the subject matter which is claimed and for which a patent is sought on the invention entitled in:

METHOD OF MAKING CAVITIES IN A SEMICONDUCTOR WAFER

and for which a patent application:

- ☒ is attached hereto and includes amendment(s) filed on _____ (if applicable)
☐ was filed in the United States on as Application No. _____ (declaration not accompanying application) with amendment(s) filed on _____ (if applicable)
☐ was filed as PCT international Application No. _____ on _____ and was amended under PCT Article 19 on _____ (if applicable)

I hereby state that I have reviewed and understand the contents of the above identified application, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

EARLIEST FOREIGN APPLICATION(S), IF ANY, FILED PRIOR TO THE FILING DATE OF THE APPLICATION			
APPLICATION NUMBER	COUNTRY	DATE OF FILING (day, month, year)	PRIORITY CLAIMED
0216049	France	December 20, 2002	<input checked="" type="checkbox"/> YES <input type="checkbox"/> NO
0216409			<input type="checkbox"/> YES <input type="checkbox"/> NO

I hereby claim the benefit under Title 35, United States Code, § 119(e) of any United States provisional application(s) listed below.



PROVISIONAL APPLICATION NUMBER	FILING DATE
60/448,124	February 20, 2003

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code § 112, I acknowledge the duty to disclose information known to me which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

NON-PROVISIONAL APPLICATION NO.	FILING DATE	STATUS		
		PATENTED	PENDING	ABANDONED

* for use only when the application is assigned to a company, partnership or other organization.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

201	FULL NAME OF INVENTOR	LAST NAME SCHWARZENBACH	FIRST NAME Walter	MIDDLE NAME	
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		SIGNATURE OF INVENTOR 201 		DATE 26/04/04	
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		SIGNATURE OF INVENTOR 202 		DATE 28/4/2004	
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	POST OFFICE ADDRESS	STREET	CITY	STATE OR COUNTRY	ZIP CODE
		SIGNATURE OF INVENTOR 203		DATE	



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Bib Data Sheet

CONFIRMATION NO. 9739

SERIAL NUMBER 10/733,729	FILING DATE 12/12/2003 RULE	CLASS 438	GROUP ART UNIT 2818	ATTORNEY DOCKET NO. 4717-9200
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APPLICANTS

Walter Schwarzenbach, St. Nazaire Les Eymes, FRANCE;
Christophe Maleville, La Terrasse, FRANCE;

**** CONTINUING DATA *******
This appln claims benefit of 60/448,124 02/20/2003 *DN*

**** FOREIGN APPLICATIONS *******
FRANCE 0216049 12/20/2002 *DN*

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
**** 03/17/2004**

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY FRANCE	SHEETS DRAWING 3	TOTAL CLAIMS 26	INDEPENDENT CLAIMS 4
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged	Examiner's Signature	Initials		

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TITLE
Method of making cavities in a semiconductor wafer

FILING FEE	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time)
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